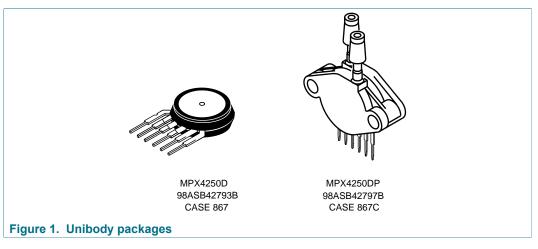
0 to 250 kPa, Differential, gauge pressure sensor, on-chip signal conditioned, temperature compensated and calibrated Rev. 8.0 — 25 July 2017 Data sheet: technical data

### **1** General description

The MPX4250D series piezoresistive transducer is a state-of-the-art monolithic silicon pressure sensor designed for a wide range of applications, particularly those employing a microcontroller or microprocessor with A/D inputs. This transducer combines advanced micromachining techniques, thin-film metallization, and bipolar processing to provide an accurate, high-level analog output signal that is proportional to the applied pressure. The small form factor and high reliability of on-chip integration make the NXP sensor a logical and economical choice for the automotive system engineer.

### 2 Features

- · Differential and gauge applications available
- 1.4 % maximum error over 0 °C to 85 °C
- Patented silicon shear stress strain gauge
- Temperature compensated over –40 °C to +125 °C
- · Offers reduction in weight and volume compared to existing hybrid modules
- Durable epoxy unibody element
- Available in two unibody packages



### 3 Typical applications

· Ideally suited for microprocessor or microcontroller-based systems



# **MPX4250D**

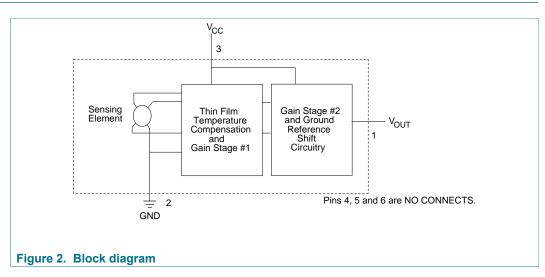
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#### **Ordering information** 4

#### Table 1. Ordering information

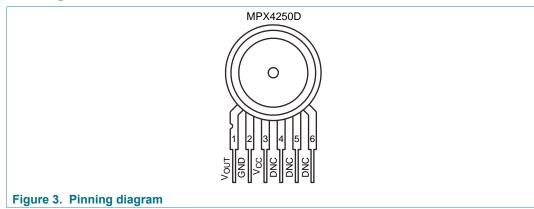
Device name	Package Package		# of Ports		Pressure type			Device	
	Options	Name	None	Single	Dual	Gauge	Differential	Absolute	marking
MPX4250D	Tray	98ASB42793B	•				•		MPX4250D
MPX4250DP	Tray	98ASB42797B			•		•		MPX4250DP

#### **Block diagram** 5



#### **Pinning information** 6

6.1 Pinning



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### 6.2 Pin description

#### Table 2. Pin descriptions

Symbol	Pin	Description
V <sub>OUT</sub>	1	Output voltage
GND	2	Ground
V <sub>CC</sub>	3	Voltage supply
DNC	4	Do not connect to external circuitry or ground
DNC	5	Do not connect to external circuitry or ground
DNC	6	Do not connect to external circuitry or ground

#### Mechanical and electrical specifications 7

### 7.1 Maximum ratings

#### Table 3. Maximum ratings

Exposure beyond the specified limits may cause permanent damage or degradation to the device.

Rating	Symbol	Value	Unit
Maximum pressure (P1 > P2)	P <sub>MAX</sub>	1000	kPa
Storage temperature	T <sub>STG</sub>	-40 to +125	°C
Operating temperature	T <sub>A</sub>	-40 to +125	°C

Figure 2 shows a block diagram of the internal circuitry integrated on a pressure sensor chip.

### 7.2 Operating characteristics

#### Table 4. Operating characteristics

 $(V_{CC} = 5.1 \text{ Vdc}, T_A = 25 \text{ °C}$  unless otherwise noted, P1 > P2. Decoupling circuit shown in Figure 5 required to meet electrical specifications.)

Symbol	Characteristic	Min	Тур	Max	Unit
P <sub>OP</sub>	Pressure range <sup>[1]</sup>	0	—	250	kPa
V <sub>CC</sub>	Supply voltage <sup>[2]</sup>	4.85	5.1	5.35	Vdc
Ι <sub>ο</sub>	Supply current	—	7.0	10	mAdc
V <sub>off</sub>	Minimum pressure offset <sup>[3]</sup> (0 °C to 85 °C)	0.139	0.204	0.269	Vdc
V <sub>FSO</sub>	Full scale output <sup>[4]</sup> (0 °C to 85 °C)	4.844	4.909	4.974	Vdc
V <sub>FSS</sub>	Full scale span <sup>[5]</sup> (0 °C to 85 °C)	—	4.705		Vdc
_	Accuracy <sup>[6]</sup> (0 °C to 85 °C)	—	—	±1.4	%V <sub>FSS</sub>
ΔV/ΔΡ	Sensitivity	—	18.8		mV/kPa
t <sub>R</sub>	Response time <sup>[7]</sup>	_	1.0		ms
I <sub>o+</sub>	Output source current at full scale output	—	0.1		mAdc
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Symbol	Characteristic	Min	Тур	Мах	Unit
—	Warm-up time <sup>[8]</sup>	—	20		ms
—	Offset stability <sup>[9]</sup>	_	±0.5		%V <sub>FSS</sub>

[1] 1.0 kPa (kiloPascal) equals 0.145 psi.

- [2] Device is ratiometric within this specified excitation range.
- [3] Offset (V<sub>off</sub>) is defined as the output voltage at the minimum rated pressure.
- [4] Full scale output (V<sub>FSO</sub>) is defined as the output voltage at the maximum or full rated pressure.
- [5] Full scale span (V<sub>FSS</sub>) is defined as the algebraic difference between the output voltage at full rated pressure and the output voltage at the minimum rated pressure.
- [6] Accuracy (error budget) consists of the following:
  - Linearity: Output deviation from a straight line relationship with pressure over the specified pressure range.
  - Temperature hysteresis: Output deviation at any temperature within the operating temperature range, after the
  - temperature is cycled to and from the minimum or maximum operating temperature points, with zero pressure applied.
    Pressure hysteresis: Output deviation at any pressure within the specified range, when this pressure is cycled to and from the minimum or maximum rated pressure, at 25 °C.
  - TcSpan: Output deviation over the temperature range of 0 °C to 85 °C, relative to 25 °C.
  - TcOffset: Output deviation with minimum rated pressure applied, over the temperature range of 0 °C to 85 °C, relative to 25 °C.
- Variation from nominal: The variation from nominal values, for offset or full scale span, as a percent of  $V_{FSS}$ , at 25 °C. [7] Response time is defined as the time for the incremental change in the output to go from 10 % to 90 % of its final value
- when subjected to a specified step change in pressure. 8] Warm-up time is defined as the time required for the product to meet the specified output voltage after the pressure has
- [8] Warm-up time is defined as the time required for the product to meet the specified output voltage after the pressure has been stabilized.
   [9] Other tability is the conducted state to be a stabilized to 4000 hours of subsciences and in a state of the state of th
- [9] Offset stability is the product's output deviation when subjected to 1000 hours of pulsed pressure, temperature cycling with bias test.

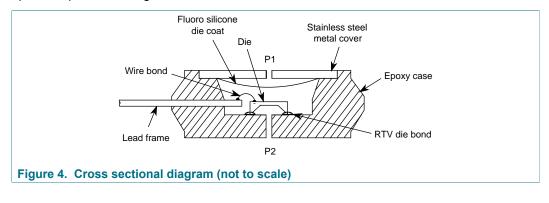
### 8 On-chip temperature compensation and calibration

Figure 4 illustrates the differential/gauge pressure sensing chip in the basic chip carrier (98ASB42793B). A fluorosilicone gel isolates the die surface and wire bonds from the environment, while allowing the pressure signal to be transmitted to the sensor diaphragm.

The MPX4250D series pressure sensor operating characteristics and internal reliability and qualification tests are based on use of dry air as the pressure media. Media, other than dry air, may have adverse effects on sensor performance and long-term reliability. Contact the factory for information regarding media compatibility in your application.

<u>Figure 5</u> shows the recommended decoupling circuit for interfacing the output of the integrated sensor to the A/D input of a microprocessor or microcontroller.

Figure 6 shows the sensor output signal relative to pressure input. Typical, minimum, and maximum output curves are shown for operation over a temperature range of 0 °C to 85 °C using the decoupling circuit shown in Figure 5. The output will saturate outside of the specified pressure range.



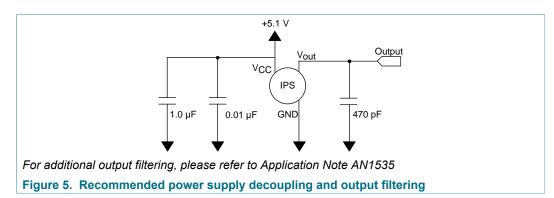
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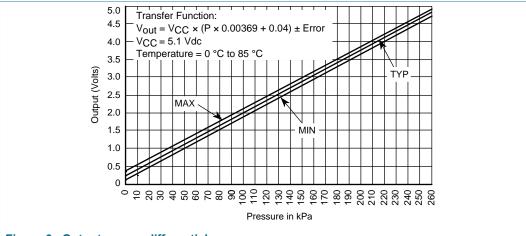
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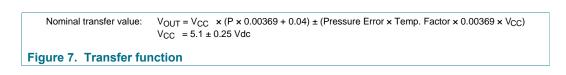
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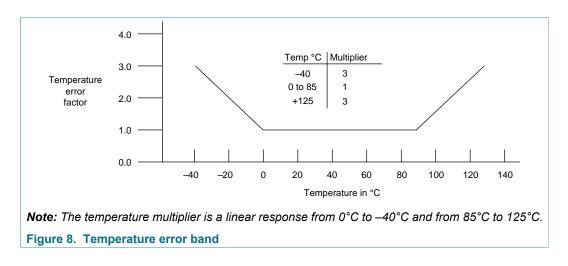
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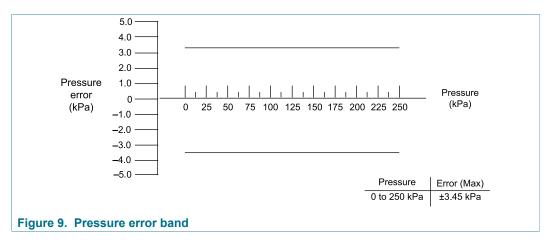
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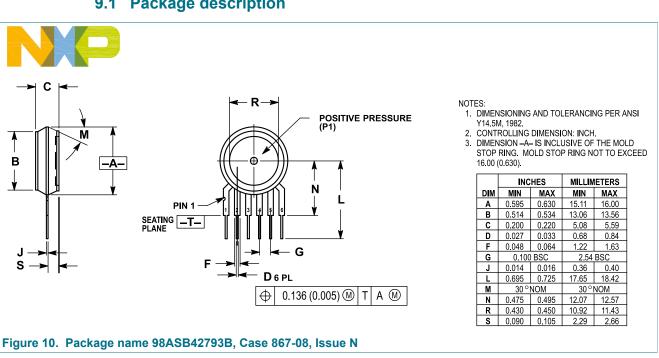
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#### **Package information** 9



#### Package description 9.1

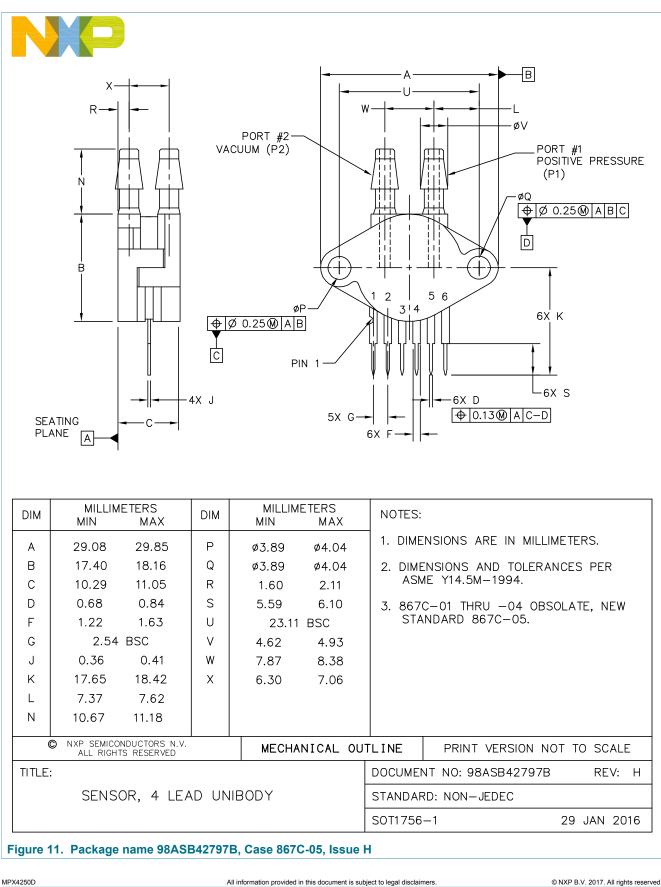
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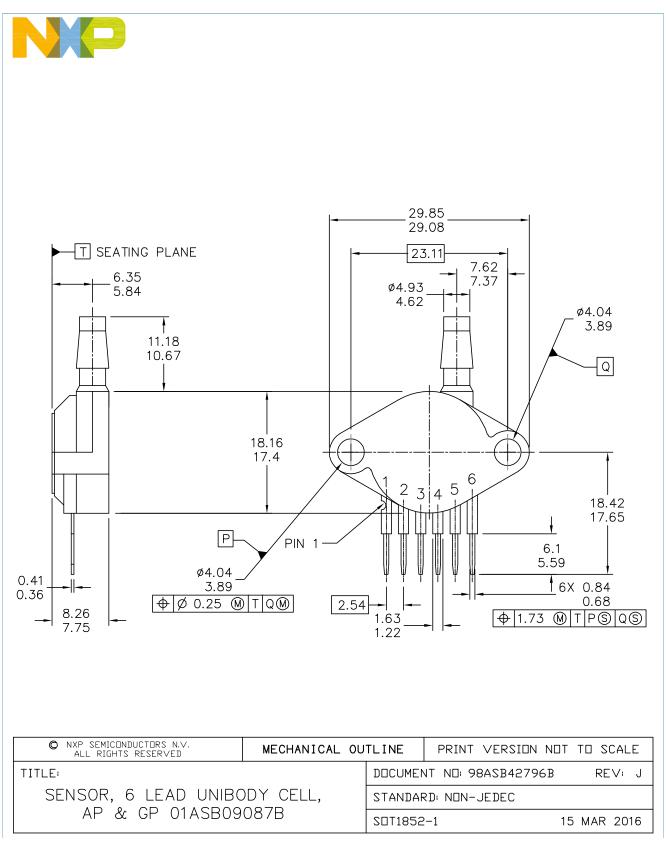
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NOTES:

- 1. DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994.
- 3. 867B-01 THRU -3 OBSOLETE, NEW STANDARD 867B-04.

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TITLE:		DOCUME	NT NO: 98ASB42796B	REV: J	
SENSOR, 6 LEAD UNIBODY CELL,			STANDARD: NON-JEDEC		
AP & GP 01ASB09087B		SOT1852	2—1	15 MAR 2016	
Figure 12. Package name 98ASB42796B, Case 867B-04, Issue J					

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## 10 Revision history

Document ID	Release date	Data sheet status	Change notice	Supercedes
MPX4250D v.8.0	20170725	Technical data	—	MPX4250 v.7.0
Modifications:	<ul> <li>NXP Semiconductors.</li> <li>Legal texts have been</li> <li>Revised "MPX4250" to</li> <li>Updated the documer Pressure Sensor On-0 "20 to 250 kPa, Manife compensated and cali</li> <li>Added Figure 1 "Unibo Updated Table 1 "Ord</li> <li>Revised Figure 2 "Blo – Changed Vs to V<sub>CC</sub></li> <li>Revised the note to</li> <li>Added pin description</li> <li>Changed Vs to V<sub>CC</sub> in in Section 7.2 "Operat</li> <li>Updated the figures in follows:</li> <li>Figure 4 "Cross sec</li> <li>Figure 5 "Recommer</li> <li>Figure 6 "Output ver</li> <li>Figure 9 "Pressure of Updated the figures at</li> <li>Figure 10 "Package</li> <li>Figure 11 "Package</li> </ul>	a adapted to the new com o "MPX4250D." at title from "Integrated S Chip Signal Conditioned, old absolute pressure se ibrated." ody packages" in Section ering information" in Sec ck diagram " in Section & read "Pins 4, 5 and 6 ar tion as Figure 3 "Pinning s in Table 2 "Pin descrip the description and with ting characteristics". a Section 8 "On-chip tem tional diagram (not to se ended power supply deco rsus differential pressure unction" error band"	npany name where app ilicon Pressure Sensor Temperature Compen nsor, on-chip signal co <u>n 2 "Features"</u> . <u>stion 4 "Ordering inform</u> <u>5 "Block diagram" as fo</u> <u>e NO CONNECTS"</u> <u>diagram" in Section 6.</u> <u>diagram" in Section 6.2 "P</u> <u>in the body of Table 4</u> <u>perature compensation</u> <u>ale)"</u> <u>oupling and output filter</u> <u>ase 867-08, Issue N"</u> <u>Case 867C-05, Issue H</u>	Manifold Absolute sated and Calibrated" to nditioned, temperature nation". llows: <u>1 "Pinning".</u> in description". "Operating characteristics" and calibration" as ing".
MPX4250 v.7.0	20090131	Technical data		MPX4250 v.6.0

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Fig. 12.	Package name	98ASB42796B,	Case	

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